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An STM study of Molecular Exchange Processes in Organic Thin Film Growth

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The growth of a fullerene derivative (PCBM) on top of a layer of a tetrathiafulvalene (TTF) derivative previously deposited on Au(111) has been studied by Scanning Tunneling Microscopy (STM). The results show that the preferential interaction with the gold substrate induces the exchange of PCBM molecules with exTTF monolayer, expelling exTTF molecules to the outer surface. This exchange processes is forbidden when the thickness of the exTTF layer increases above the monolayer, and the larger surface energy of PCBM leads to the growth of 3D islands.

As the field of organic electronic evolves, it is becoming increasingly evident that the efficiency of the final devices is strongly dependent on the quality and the actual composition of the different interfaces within. The realization that small changes in local environment at the molecular level in the interface can produce important changes in electronic and optical properties has prompted the study of both organic-inorganic and organic-organic heteroepitaxy. However, when compared to all-inorganic epitaxy, the field is still in its infancy: the existence of many additional degrees of freedom makes drawing general conclusions from a particular system very difficult.

Besides epitaxy, that strictly speaking refers only to the orientation and crystallinity of the growing layer with respect to the substrate, others factors that may affect interface quality are the roughness and/or interdiffusion at the interface. Although roughness has been treated in some cases, there are very few reports on interdiffusion, and seldom at the molecular level.

In this manuscript, we report an STM study of the exchange processes that take place when PCBM (phenyl-C61-butyric acid methyl ester, see the inset in Figure 1a) is sublimated on top a layer of a TTF derivative (2-[9-(1,3-dithiol-2-ylidene)anthracen-10(9H)-ylidene]-1,3-dithiole, exTTF, see the inset in Figure 1b) epitaxially grown on Au(111). By comparing with the previous studies on the growth of PCBM on Au(111) and exTTF on Au(111), the results presented here show how the deposition of PCBM transforms partially the exTTF/Au(111) into a PCBM/Au(111) interface by displacing a large fraction of the exTTF molecules to the outer surface.

PCBM, a fullerene derivative, is a well-known strong electron acceptor commonly used in bulk heterojuctions solar cells. At room temperature the PCBM molecules are highly mobile on the gold substrate, which allows them to react with the exTTF monolayer and start the exchange process.
the Au(111) surface. If the substrate temperature is lowered to 150 K, different structures are formed depending on the local coverage. Close to the monolayer, a disordered structure is found, which only exhibits a short-range hexagonal order (Figure 1a). exTTF, on the other hand, is a relatively strong electron donor molecule. When deposited on Au(111) the exTTF molecules form striped islands composed of ordered arrays of 1D molecular rows that follow the compact direction of the substrate. When increasing the coverage, these islands coalesce, forming a number of alternating domains with different orientations and a typical width of 50 nm (Figure 1b). Second and third layer growth also proceeds in the form of 1D rows in registry with the first monolayer, but their lateral arrangement lacks the long-range order observed of the first monolayer (see Figure 1c).

The growth of mixed PCBM-exTTF 2D layers has also been reported. After depositing ~0.5 ML of exTTF on top of an already grown 0.5 ML of PCBM the STM images (Figure 1d) show that exTTF and PCBM do not mix; on the contrary, exTTF disturbs the PCBM arrangement to form elongated islands similar to the ones formed in the absence of PCBM, confining PCBM to the space between the islands. The amount of exTTF exceeding the available free space grows in the form of second layer on top of the exTTF islands. A similar result is obtained if exTTF is deposited before PCBM. The resulting morphology, a lateral superlattice of interdigitated nanoscale stripes with a characteristic width of about 10-20 nm, has been predicted to optimize the efficiency of bulk-heterojunction organic solar cells.

In an attempt to build an exTTF-PCBM vertical superlattice, we have deposited PCBM on top of a complete monolayer of exTTF. Immediately after depositing ~0.15 ML of PCBM, the STM images (Figure 2a) show that the PCBM molecules form small, disordered clusters over the exTTF layer. These clusters seem to nucleate preferentially, but not exclusively, on the domain frontiers of the exTTF layer. However, images taken 30 min after deposition, with the sample kept at 150 K, show that the morphology of the second layer has changed substantially (Figure 2b). Instead of forming disordered clusters, the second layer molecules form 1D rows in registry with the first layer exTTF rows, exactly as second layer exTTF molecules do. Also, the slightly elongated shape of second layer molecules bears a strong resemblance with the shape of second layer molecules in exTTF-only films (see Figure S2 in the SI). The possibility of being second layer PCBM molecules epitaxially grown on the exTTF layer (it has been reported that C$_{60}$ can grow epitaxially on other organic systems) can be excluded because the separation between molecules along the rows is 7.7 Å (as in C$_{60}$, the minimum separation between two PCBM molecules is 10 Å). Moreover, inspection of the first molecular layer shows the appearance of embedded clusters of molecules, larger in size than exTTF molecules, and with a short range hexagonal order (see the circled areas in Figures 2b and 2d and Figure S3). We thus conclude that PCBM molecules initially on top of the exTTF layer are now in direct contact with the Au(111) surface in the first layer, while some exTTF molecules have been displaced from the first to the second layer. That is, PCBM molecules have exchanged place with the exTTF molecules underneath, which have, in turn, themselves diffused over the surface to form the characteristic second layer rows. Please note that, although both exTTF and PCBM were deposited with the substrate held at room temperature, STM measurements were carried out at 150 K. At this temperature, the exTTF layer is almost completely frozen, as evidenced by the sequencing imaging of the same area of the sample: the naturally occurring vacancies present in the exTTF layer and visible like dark spots in Figure 1b do not show any displacement from one image to the next.

Similar results are obtained for higher PCBM coverages. Figure 2c, taken after depositing ~0.15 ML of PCBM on top of the previous sample, shows the same disordered clusters of molecules. Once again, after a similar interval of time, the PCBM molecules exchange places with the exTTF molecules, going inside the exTTF layer. Correspondingly, the amount of exTTF now in the second layer is, within the error limits, equal to the total amount of deposited PCBM (Figure 2d).

Figure 2. left) STM images (59 nm × 66 nm) of the Au(111) surface taken immediately after depositing a) 0.15 ML; c) 0.30 ML; and e) 0.45 ML of PCBM on a complete layer of exTTF; right) STM images of the samples shown in the left panel but taken ~30 minutes after deposition. (Measurement temperature: 150 K.)

For larger coverages (using the same deposition rate), the deposition time was large enough so that the amount of exchange processes that had already taken place when the STM
measurement started was already significant. Figure 2e was taken after depositing ~0.45 ML of PCBM (120 min) on the exTTF layer. The first measurements already show a mixed second layer composed of exTTF and PCBM molecules; but also in this case, after 30-40 minutes, the exchange process was complete (Figure 2f), and the second layer was exclusively composed of exTTF molecules.

Although an influence of the scanning tip on the dynamics of the exchange processes cannot be completely ruled out, we can certainly exclude it as the main driving force: in every case, ~30-40 minutes after deposition, all the second layer molecules were exTTF, and PCBM could only be found in the first layer, even when moving to a new, fresh region of the sample.

Place exchange is fairly common in metal-on-metal epitaxy, especially in fcc (100) and (110) surfaces, where it seems to be related to the atomistic mechanism of surface diffusion. These processes can lead to surface alloying, even for metals almost immiscible in bulk, or to the formation of islands of the deposited material within the first surface layer. The driving force for surface exchange processes has been attributed to different factors, such as a higher surface energy of the deposited material, a negative interfacial energy that would favour interfacial mixing, or to the strain caused by atomic size mismatch, which can be considerably reduced by surface-confined mixing. In many cases, exchange processes can lead to surfactant-assisted epitaxial growth, since the floating layer can promote epitaxial growth by modifying the diffusion mechanism of the growing layer.

![Figure 3](image-url)

**Fig. 3.** a) STM image (236 nm × 264 nm) of ~2.5 ML of exTTF on the Au(111) surface; b) STM image (236 nm × 264 nm) taken after depositing ~0.5 ML of PCBM on the sample in (a). (Measurement temperature: 300 K.)

The place exchange at the level of the monolayer is driven by the difference in the interaction with the Au(111) substrate; while the adsorption energy of exTTF on Au(111) is only of 0.32 eV/molecule, the expected adsorption energy of PCBM is substantially larger, since for C_{60} on Au(111) is of the order of 1.9 eV/molecule. In order to determine the dependence of the exchange process on the thickness of the exTTF layer, we have deposited ~0.5 ML of PCBM on top of ~2.5 ML-thick film of exTTF (Figure 3a). The STM images (Figure 3b) seem to indicate that now the PCBM molecules have not been able to diffuse under the exTTF layer. Close-up images (see Figure S4 in the SI) show that the exTTF layer remains undistorted. The PCBM molecules have diffused to the domain frontiers forming large 3D clusters, with an average lateral size of ~50 Å and an apparent height of ~16 Å. This type of growth is commonly known as “Volmer-Weber”, or island growth, and takes place when the atoms (or molecules) of the deposited material (PCBM) are more strongly bound to each other than to the substrate (exTTF). The requirement for island growth can also be expressed, in terms of the surface free energy $\gamma_0$, as $\gamma_{\text{exTTF}} < \gamma_0 - \gamma_{\text{PCBM}}$, where $\gamma_0$ is the interfacial energy which suggests that the surface free energy of a PCBM layer and/or the interfacial energy are larger than the one of exTTF. The surface free energies are proportional to the cohesive energies and the observation of 3D growth of PCBM on exTTF is in agreement with values for the cohesive energy of PCBM (1.3 eV) and of the parent compound TTF (~1 eV). With the values above, PCBM molecules are much more strongly bound to the gold substrate than to each other and, accordingly, the growth of PCBM on Au(111) is not of the island growth type, as shown in Figure 1a. Then, the high energetic cost of having a flat PCBM layer on top of a exTTF layer can be avoided either by forming PCBM 3D clusters, either by binding to the gold layer. When grown on 1 ML of exTTF, the PCBM molecules can exchange place with the exTTF molecules to bind strongly to Au(111), but 2 ML of exTTF already constitute a barrier large enough to prevent the diffusion of PCBM to the gold layer (as Figure 3 seems to indicate) and 3D island growth takes over.

On the other hand, despite the relatively strong $\pi-\pi$ interaction between fullerenes and exTTF derivatives, PCBM and exTTF do not mix on the gold surface (as shown in Figure 1d), one of the reasons probably being that they are shape and structurally different from those previously reported related to alloying, since in the present case it is the presence of a third material, the gold substrate, the ultimate responsible for the intermixing between PCBM and exTTF.

In summary, we have shown that when PCBM is deposited on top of a exTTF monolayer previously adsorbed on Au(111), there are exchange processes between the PCBM and exTTF molecules, the former ending up embedded within the exTTF layer. This exchange processes is related to the larger adsorption energy of PCBM on Au(111) layer. The exchange process is limited to the first monolayer, as the higher surface free energy of PCBM takes over and leads to the growth of 3D islands of PCBM on exTTF for larger thickness.

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**Notes and references**

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